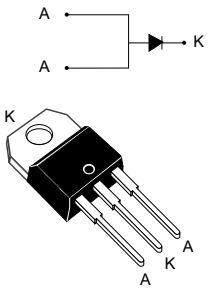
STPS30100ST

Datasheet

100 V power Schottky rectifier



TO-220AB

Features

- Low V_F
- Good trade-off between leakage current and forward voltage drop
- High frequency operation
- Avalanche capability specified
- ECOPACK®2 compliant

Applications

- Switching diode
- SMPS
- DC/DC converter
- LED lighting
- Desktop power supply

Description

This single Schottky rectifier is ideal for high frequency switch mode power supply.

Housed in a TO-220AB package, the STPS30100ST is optimized for use in notebook and game station adaptors, providing an improved efficiency at both low and high load.

Product status link	
STPS30100ST	
Product summary	
Symbol	**Value**
$I_{F(AV)}$	30 A
V_{RRM}	100 V
T_j (max.)	150 °C
V_F (typ.)	0.605 V

1 Characteristics

Table 1. Absolute ratings (limiting values with terminals 1 and 3 short circuited at T_{amb} = 25 °C, unless otherwise specified)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		100	V
$I_{F(RMS)}$	RMS forward current		60	A
$I_{F(AV)}$	Average forward current	T_c = 125 °C, δ = 0.5	30	A
I_{FSM}	Surge non repetitive forward current	t_p = 10 ms sinusoidal	300	A
P_{ARM}	Repetitive peak avalanche power	t_p = 10 µs, T_j = 125 °C	1900	W
T_{stg}	Storage temperature range		-65 to +175	°C
T_j	Maximum operating junction temperature(1)		150	°C

1. *$(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.*

Table 2. Thermal resistance parameters

Symbol	Parameter	Max. value	Unit
$R_{th(j-c)}$	Junction to case	1	°C/W

Table 3. Static electrical characteristics (terminals 1 and 3 short circuited)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
I_R(1)	Reverse leakage current	T_j = 25 °C	$V_R = V_{RRM}$	-		175	µA
		T_j = 125 °C		-	20	50	mA
		T_j = 25 °C	V_R = 70 V	-		60	µA
		T_j = 125 °C		-	10	20	mA
V_F(2)	Forward voltage drop	T_j = 25 °C	I_F = 5 A	-	0.475		V
		T_j = 125 °C		-	0.385		
		T_j = 25 °C	I_F = 10 A	-	0.555		
		T_j = 125 °C		-	0.475		
		T_j = 25 °C	I_F = 15 A	-	0.620	0.660	
		T_j = 125 °C		-	0.525	0.565	
		T_j = 25 °C	I_F = 30 A	-	0.740	0.800	
		T_j = 125 °C		-	0.605	0.655	

1. *Pulse test: t_p = 5 ms, δ < 2%*
2. *Pulse test: t_p = 380 µs, δ < 2%*

To evaluate the conduction losses, use the following equation:

$P = 0.475 \times I_{F(AV)} + 0.006 \times I_F{}^2{}_{(RMS)}$

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier

- AN4021: Calculation of reverse losses on a power diode

1.1 Characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current

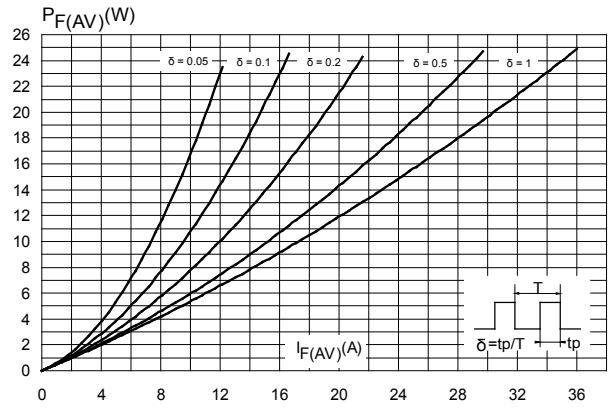


Figure 2. Average forward current versus ambient temperature (δ = 0.5)

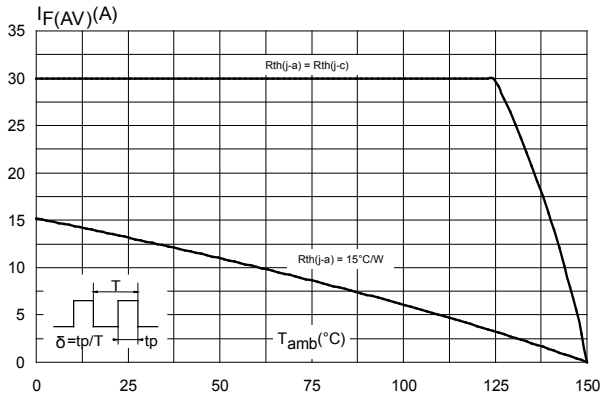


Figure 3. Normalized avalanche power derating versus pulse duration (T_j = 125 °C)

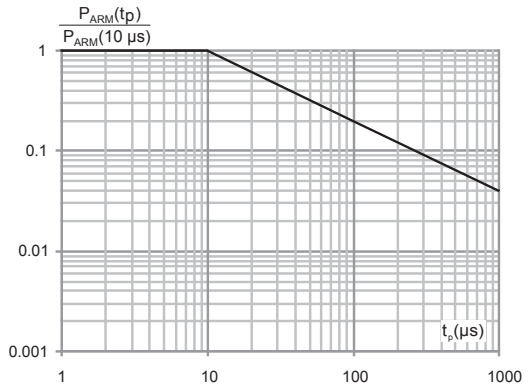


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration

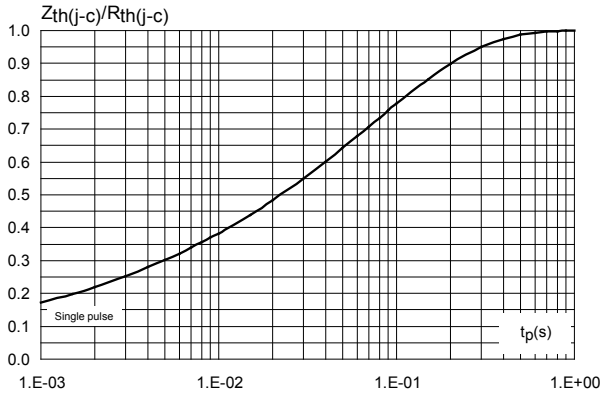


Figure 5. Reverse leakage current versus reverse voltage applied (typical values)

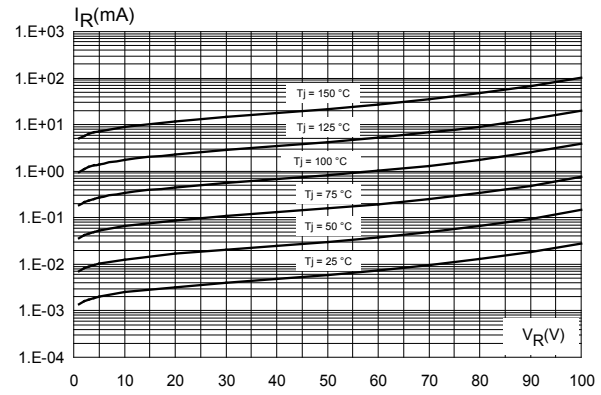


Figure 6. Junction capacitance versus reverse voltage applied (typical values)

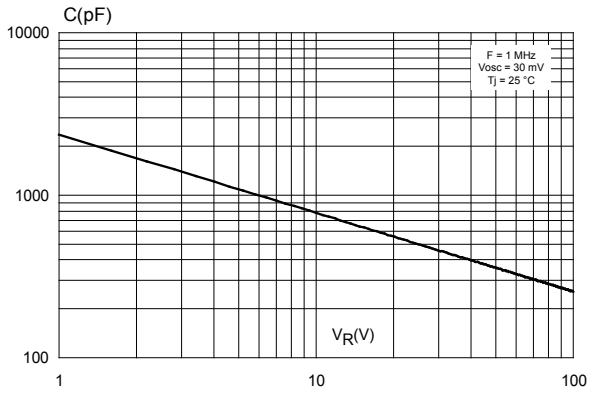


Figure 7. Forward voltage drop versus forward current (low level)

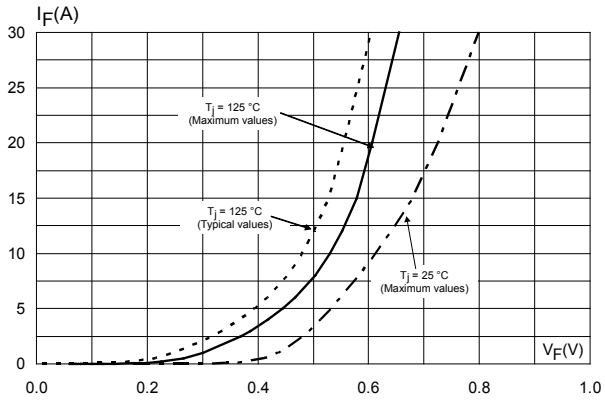
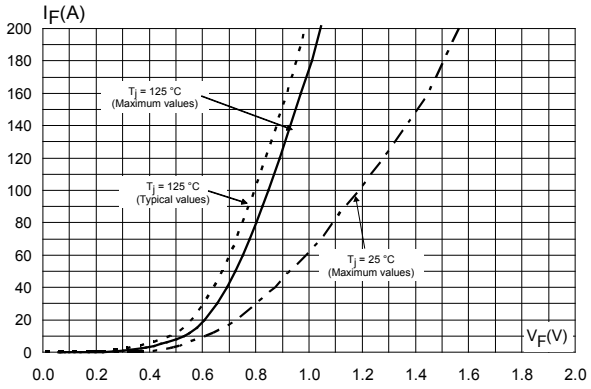


Figure 8. Forward voltage drop versus forward current (high level)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 TO-220AB package information

- Epoxy meets UL 94,V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N·m
- Maximum torque value: 0.70 N·m

Figure 9. TO-220AB package outline

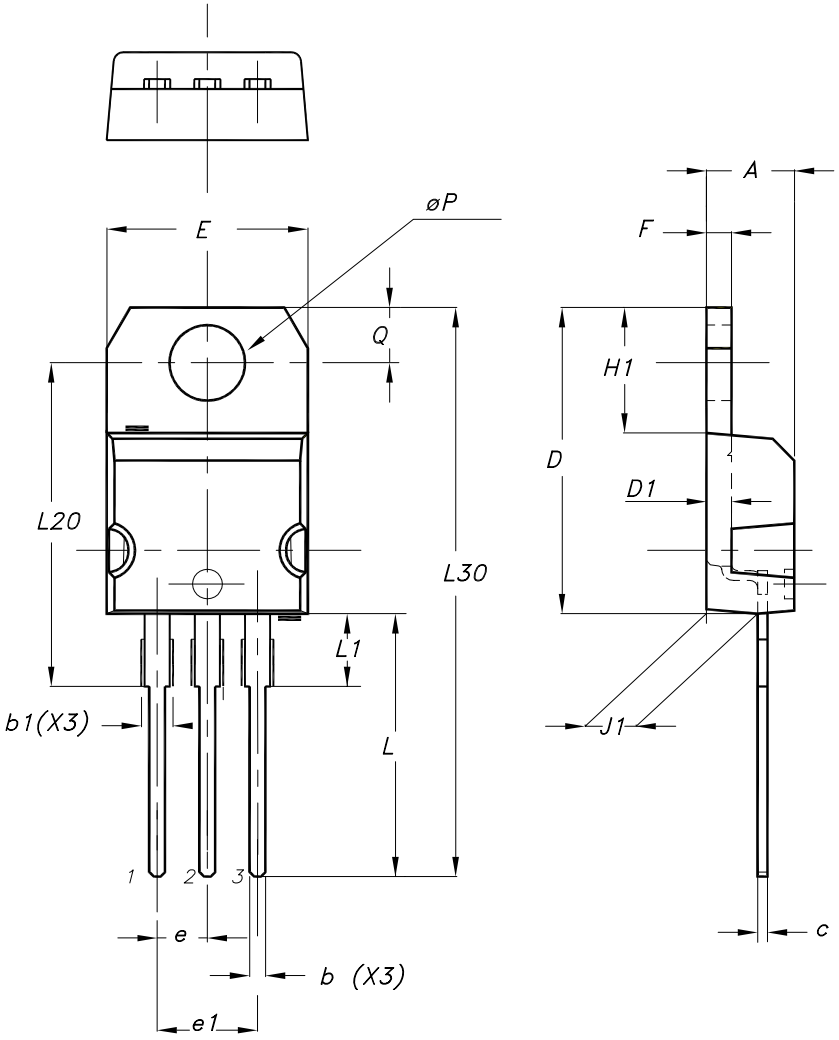


Table 4. TO-220AB package mechanical data

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
b	0.61	0.88	0.240	0.035
b1	1.14	1.55	0.045	0.061
c	0.48	0.70	0.019	0.028
D	15.25	15.75	0.600	0.620
D1	1.27 typ.		0.050 typ.	
E	10.00	10.40	0.394	0.409
e	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
F	1.23	1.32	0.048	0.052
H1	6.20	6.60	0.244	0.260
J1	2.40	2.72	0.094	0.107
L	13.00	14.00	0.512	0.551
L1	3.50	3.93	0.138	0.155
L20	16.40 typ.		0.646 typ.	
L30	28.90 typ.		1.138 typ.	
θP	3.75	3.85	0.148	0.152
Q	2.65	2.95	0.104	0.116

3 Ordering Information

Table 5. **Ordering information**

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS30100ST	STPS30100ST	TO-220AB	1.95 g	50	Tube

Revision history

Table 6. Document revision history

Date	Version	Changes
24-Oct-2006	1	First issue
11-May-2018	2	Minor text changes to improve readability. Updated Table 1. Absolute ratings (limiting values with terminals 1 and 3 short circuited at T_{amb} = 25 °C, unless otherwise specified). Removed figure 4 and figure 5. Updated Section 1.1 Characteristics (curves).

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